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MICROWAVE CORPORATION v03.1111



HMC213MS8 / 213MS8E

GaAs MMIC SMT DOUBLE - BALANCED MIXER, 1.5 - 4.5 GHz

Typical Applications

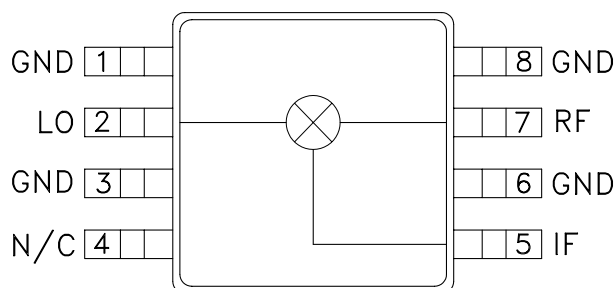
The HMC213MS8(E) is ideal for:

- LTE/4G/WiMAX Infrastructure
- Base Stations and Repeaters
- Private Land Mobile Radio (PLMR)
- ISM, Maritime & SatCom Terminals
- Microwave and Military Radios

Features

- Excellent LO to RF Isolation: 40 dB
- Excellent 2x2 Spurious Suppression: -71 dBc
- Low Conversion Loss: 8 dB
- No DC Bias & No External Matching Required
- Ideal for Upconversion & Downconversion
- MSOP8 SMT Package, 14.8 mm²

Functional Diagram



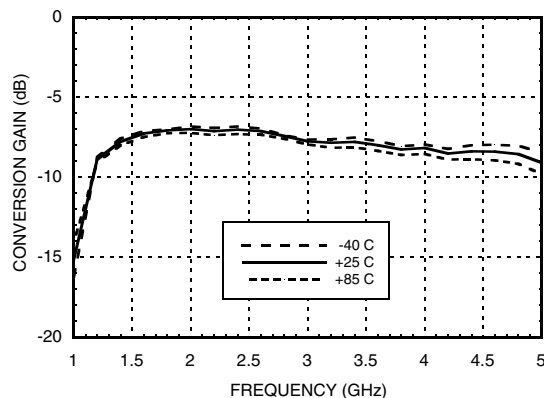
General Description

The HMC213MS8(E) is a wideband double-balanced mixer in an 8 lead plastic surface mount package. This fully integrated MMIC mixer is fabricated in a GaAs MESFET process and requires no DC bias and no external matching components. The HMC213MS8(E) mixer integrates Schottky diode mixing elements and on-chip balun transformers to deliver excellent isolation from LO to RF and from LO to IF. The wide IF bandwidth of DC to 1.5 GHz enables this mixer to be used in a wide range of general purpose applications including upconverters, downconverters, biphasic modulators, demodulators, and phase comparators. The HMC213MS8(E) operates with LO drive levels as low as +10 dBm, and exhibits excellent 2x2 spurious suppression for demanding downconversion applications.

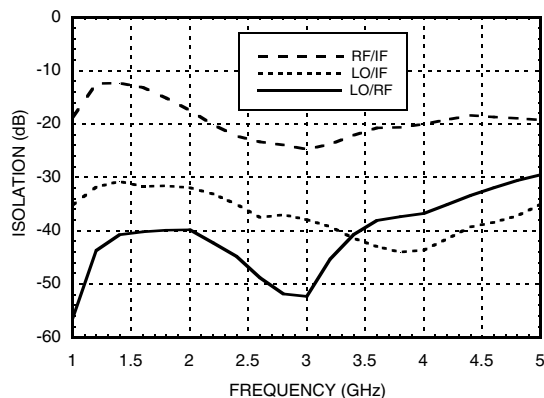
Electrical Specifications, $T_A = +25^\circ \text{C}$, As a Function of LO Drive

Parameter	LO = +13 dBm IF = 100 MHz			LO = +10 dBm IF = 100 MHz			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range, RF & LO	1.5 - 4.5			1.7 - 3.6			GHz
Frequency Range, IF	DC - 1.5			DC - 1.5			GHz
Conversion Loss		8	10		9	10.5	dB
Noise Figure (SSB)		8.5	10		9	10.5	dB
LO to RF Isolation	29	40		32	40		dB
LO to IF Isolation	27	35		26	35		dB
IP3 (Input)	16	19		14	18		dBm
1 dB Gain Compression (Input)	7	10		5	8		dBm

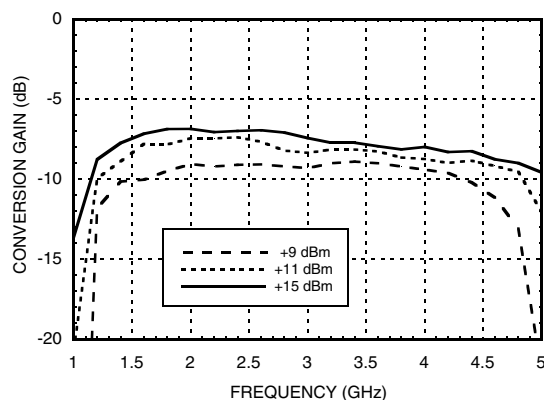
**Conversion Gain vs.
Temperature @ LO = +13 dBm**



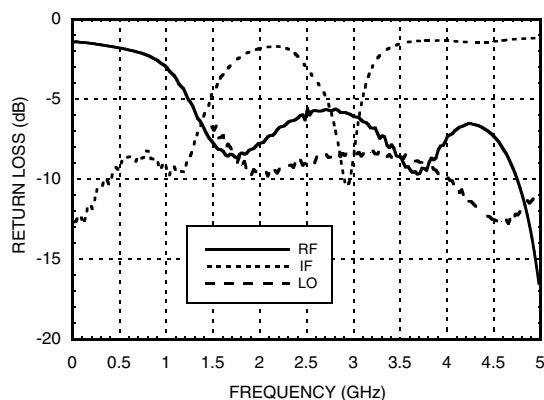
Isolation @ LO = +13 dBm



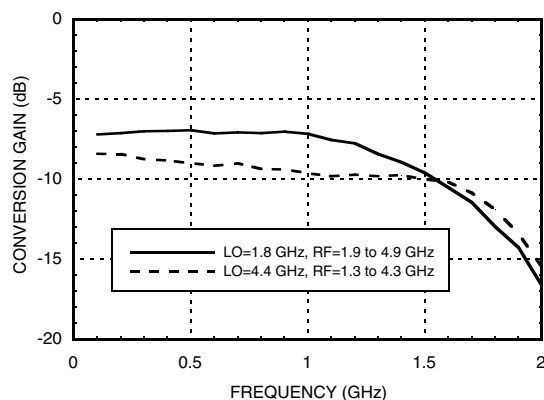
Conversion Gain vs. LO Drive



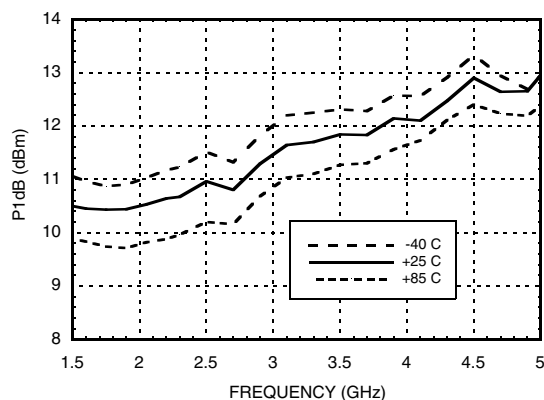
Return Loss @ LO = +13 dBm



IF Bandwidth @ LO = +13 dBm

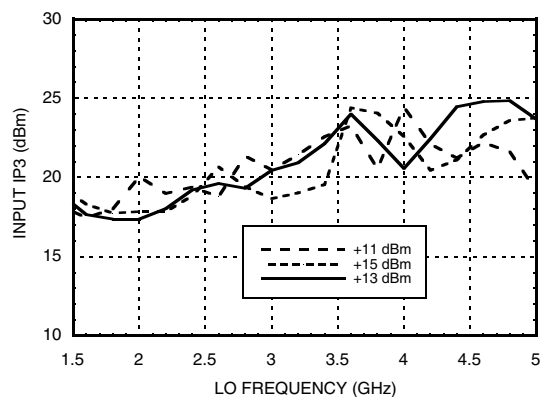


P1dB vs. Temperature @ LO = +13 dBm

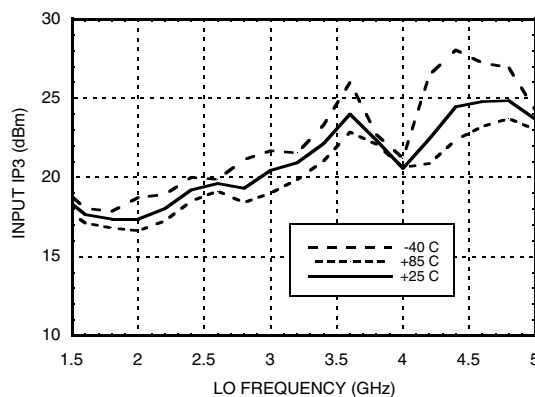


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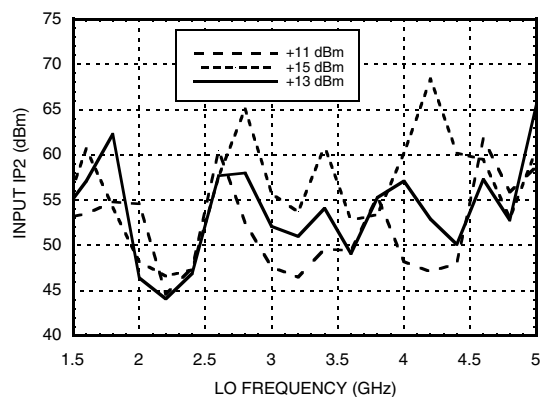
Input IP3 vs. LO Drive



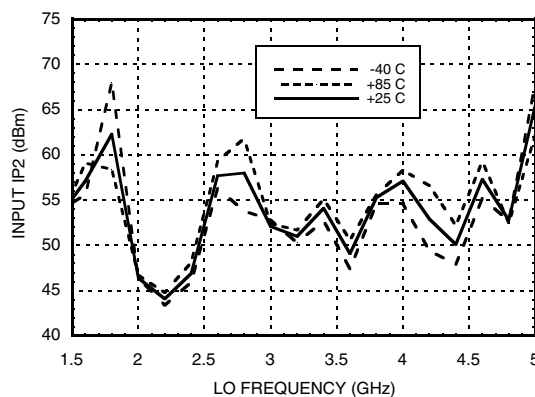
**Input IP3 vs.
Temperature @ LO = +13 dBm**



Input IP2 vs. LO Drive



**Input IP2 vs.
Temperature @ LO = +13 dBm**



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MxN Spurious Outputs

mRF	nLO				
	0	1	2	3	4
0	xx	12	22	19	52
1	13	0	44	37	60
2	74	76	71	85	71
3	94	90	92	74	84
4	>105	>105	>105	>105	>105

RF = 3.5 GHz @ -10 dBm
LO = 3.6 GHz @ +13 dBm
All values in dBc below IF power level (-1RF + 1LO)

Harmonics of LO @ RF Port

LO Freq. (GHz)	nLO Spur			
	1	2	3	4
1.5	41	34	54	53
2.0	40	29	59	59
2.5	47	29	35	62
3.0	51	34	34	62
3.5	41	43	47	65
4.0	36	47	58	70
4.5	32	52	62	72
5.0	30	53	66	70

LO = +13 dBm
Values in dBc below input LO level measured at RF Port.

Absolute Maximum Ratings

RF / IF Input	+13 dBm
LO Drive	+27 dBm
Continuous P _{diss} (T = 85 °C) (derate 10.6 mW/°C above 85 °C)	0.69 W
Thermal Resistance (Channel to package lead)	93.7 °C/W
Junction Temperature	150 °C
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS



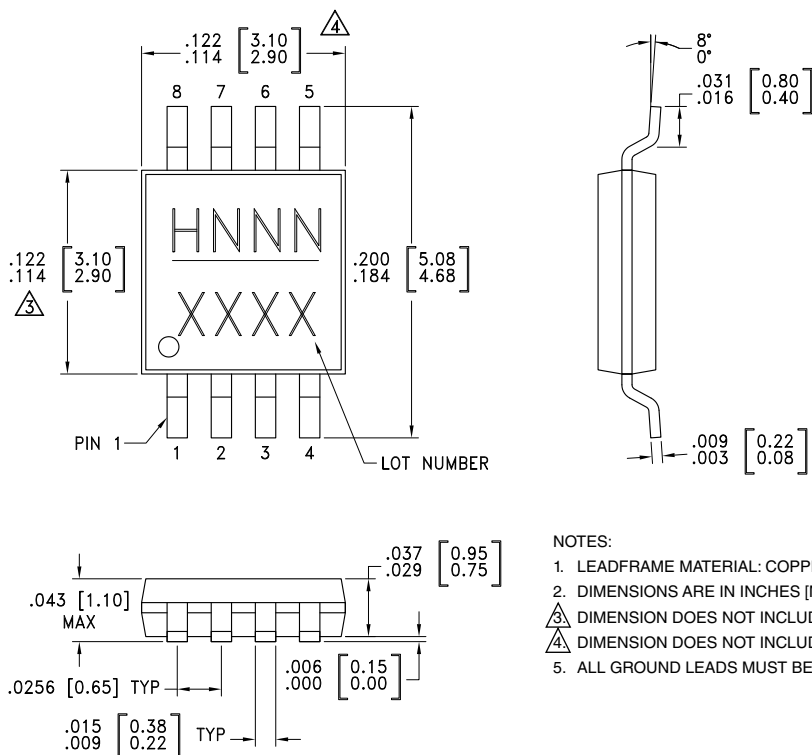
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Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

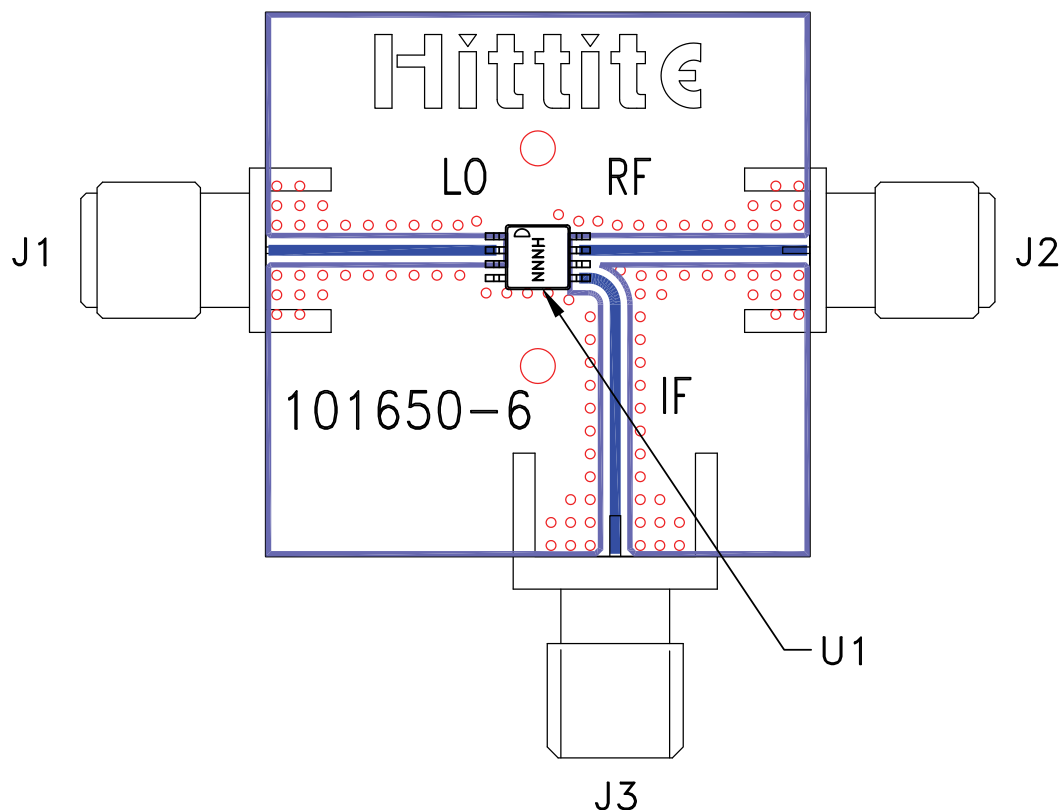
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC213MS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H213 XXXX
HMC213MS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H213 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

Evaluation PCB



List of Materials for Evaluation PCB 103350 ^[1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
U1	HMC213MS8(E) Mixer
PCB [2]	101650 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
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- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.